## NSN 5962-01-206-5871

Memory Microcircuit - Page 1 of 1



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## **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 715.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and hermetically sealed and schottky and programmable and bipolar and 3-state output and w/active pull-up **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-diode-resistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** F-5 mil-m-38510 **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Prom Shelf Life: N/a Unit Of Measure: --**Demilitarization:** Yes - demil/mli Fiig: A458a0